





	<h2>SI7431DP-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI7431DP-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 200V 2.2A PPAK SO-8</p> <p>Datenblätter:  SI7431DP-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2300 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7431DP-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 200V 2.2A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2300 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.2A (Ta)
Rds On (Max) @ Id, Vgs	174 mOhm @ 3.8A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	135nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SI7431DP-T1-E3 ist neu im Original, Suche SI7431DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7431DP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7431DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7434ADP-T1-RE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 250V POWERPAK SO-8</p>	 <p>SI7431DP-T1-GE3 Vishay / Siliconix MOSFET P-CH 200V 2.2A PPAK SO-8</p>	 <p>SI7431DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 200V 2.2A PPAK SO-8</p>	 <p>SI7434DP SI SI7434DP SI</p>
 <p>SI7431DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 200V 2.2A PPAK SO-8</p>	 <p>SI7431DP Vishay Precision Group SI7431DP VISHAY</p>	 <p>SI7431DP-T1-E3 VISHAY VISHAY QFN8</p>	 <p>SI7430DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 26A PPAK SO-8</p>

heiße Teile

Mehr

 SI7414DN-T1-GE3	 SI7414DN-T1-GE3	 SI7415DN	 SI7415DN-T1-E3	 SI7415DN-T1-E3
 SI7415DN-T1-GE3	 SI7415DN-T1-GE3	 SI7421DN	 SI7421DN-T1-E3	 SI7421DN-T1-E3
 SI7421DN-T1-GE3	 SI7421DN-T1-GE3	 SI7423DN	 SI7423DN-T1-E3	 SI7423DN-T1-E3
 SI7423DN-T1-GE3	 SI7423DN-T1-GE3	 SI7425DN-T1-E3	 SI7425DN-T1-E3	 SI7430DP-T1-E3
 SI7430DP-T1-E3	 SI7430DP-T1-GE3	 SI7430DP-T1-GE3	 SI7431DP	 SI7431DP-T1-E3
 SI7431DP-T1-GE3	 SI7431DP-T1-GE3	 SI7434DP	 SI7434DP-T1-E3	 SI7434DP-T1-E3
 SI7434DP-T1-GE3	 SI7434DP-T1-GE3	 SI7439DP-T1-E3	 SI7439DP-T1-E3	 SI7439DP-T1-GE3
 SI7439DP-T1-GE3	 SI7440DP	 SI7440DP-T1	 SI7440DP-T1-E3	 SI7440DP-T1-E3
 SI7440DP-T1-GE3	 SI7440DP-T1-GE3	 SI7442DP-T1	 SI7442DP-T1-E3	 SI7444DP-T1-GE3
 SI7445DP-T1	 SI7445DP-T1-E3	 SI7445DP-T1-E3	 SI7445DP-T1-GE3	 SI7445DP-T1-GE3

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